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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/613,331	07/07/2000	MASAMOTO TAGO	WN-2205	9072	
466 75	90 08/28/2002				
YOUNG & THOMPSON			EXAMINER		
745 SOUTH 23 ARLINGTON,	RD STREET 2ND FLO VA 22202	OOR	HOANG, QI	UOC DINH	
			ART UNIT	PAPER NUMBER	
			2818		

DATE MAILED: 08/28/2002

Please find below and/or attached an Office communication concerning this application or proceeding.



-		Application No.		Applicant(s)	
	•	09/613,331		TAGO ET AL.	3
	Offic Action Summary	Examiner		Art Unit	
	Offic Action Summary	1		2818	
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eri d for	TENED STATUTORY PERIOD FOR KEI	PLY IS SET TO EXPIR	E 3 MONTH(S) FROW	
THE M - Extens after S - If the p - If NO - Failure	RTENED STATOTOTT EMBORING RETENED STATOTOTTS TO AILING DATE OF THIS COMMUNICATION alons of time may be available under the provisions of 37 CFR IX (6) MONTHS from the mailing date of this communication. IX (6) MONTHS from the mailing date of this communication is period for reply specified above is less than thirty (30) days, a period for reply is specified above, the maximum statutory per be to reply within the set or extended period for reply will, by static ply received by the Office later than three months after the mid patent term adjustment. See 37 CFR 1.704(b).	(1.136(a). In no event, nowever reply within the statutory minimu	um of thirty (30) day	s will be considered tim the mailing date of this	nely. s communication.
Status		the BCE filed on 7/29/2	2002 .		
1)⊠	Responsive to communication(s) filed on	The RCE filed on 172015	al		
2a)□	This action is FINAL . 2b)	This action is non-min	mal matters r	prosecution as to	the merits is
3)□	This action is FINAL 2b)⊠ Since this application is in condition for al closed in accordance with the practice un	lowance except for for and address of the control o	1935 C.D. 11,	453 O.G. 213.	
Disposit	Claime				
4)⊠	Claim(s) <u>1,2,6,7 and 9-23</u> is/are pending	hdrawn from considera	ition.		
	4a) Of the above claim(s) is/are with	nulawii iioiii saisas			
5)	Claim(s) is/are allowed.				
6)[🛛	Claim(s) 1,2,6,7 and 9-23 is/are rejected.				
	idere chiected to.		ment.		
8)[Claim(s) state objects to restriction :	and/or election requires		•	
A-nling	tion Paners				
9)[The specification is objected to by the Exa	arriller.	ted to by the E	xaminer.	
10)] The drawing(s) filed on is/are: a)L	accepted of b) be he	eld in abeyance	. See 37 CFR 1.8	5(a).
	Applicant may not request that any objection The proposed drawing correction filed on	is: a) approv	red b) disar	proved by the Ex	caminer.
11)[- drawing correction filed on	13. 4/13	•		
	transported corrected drawings are require	d in reply to a			
12)[The oath or declaration is objected to by	HIC Examinor.			
			35 U.S.C. § 1	19(a)-(d) or (f).	
13)[Acknowledgment is made of a claim for 	toreign priority under s	00 0.0.0.	• • •	
.5/1	— * None of				
		cuments have been rec	coived in Ann	lication No	<u> </u>
	1. Certified copies of the priority do2. Certified copies of the priority do	cuments have been re	have been re	ceived in this Na	ational Stage
	3. Copies of the certified copies of	ional Bureau (PCT Rule	e 17.2(a)).	ceived.	
	application from the Internat * See the attached detailed Office action	demostic priority under	r 35 U.S.C. §	119(e) (to a prov	visional application)
14)	□ Acknowledgment is made of a claim for	dolliesuc priority arrange	ation has bee	en received.	
15	☐ Acknowledgment is made of a claim for a) ☐ The translation of the foreign lang☐ Acknowledgment is made of a claim for	domestic priority unde	er 35 U.S.C. §	§ 120 and/or 12	1.
Attac	hment(s)			PTO-413)	Paper No(s)
1) 🛛	Notice of References Cited (PTO-892)	O-948) 5)	Notice of In	formal Patent Applic	ation (PTO-152)
3) 🗵	Notice of Draftsperson's Patent Drawing Nevert (Information Disclosure Statement(s) (PTO-1449) Par				Part of Paper No. 10

Application/Control Number: 09/613,331

Art Unit: 2818

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after allowance or after an Office action under Ex Parte Quayle, 25 USPQ 74, 453 O.G. 213 (Comm'r Pat. 1935). Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, prosecution in this application has been reopened pursuant to 37 CFR 1.114. Applicant's submission filed on 7/29/02 has been entered.

Information Disclosure Statement

2. The Information Disclosure Statement filed on 7/03/02 and 7/29/02 has been considered.

Allowable Subject Matter

3. The indicated allowability of claims 1, 2, 6, 7 and 9-23 is withdrawn in view of the newly discovered reference(s) to Saitou et al. Rejections based on the newly cited reference(s) follow.

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 5. Claims 1-2, 6, 7 and 9-23 are rejected under 35 U.S.C. 102(b) as anticipated over Saitou et al. (U.S. Patent No. 5,162,240).

•Application/Control Number: 09/613,331 Page 3

Art Unit: 2818

Regarding claims 1, 2, 6, 9, 12-17, 19 and 23, Saitou et al., Figures. 1-13, and related text on col. 1-20 which discloses a method of manufacturing a system semiconductor device comprising: forming a system LSI cell portion 30 which includes a plurality of functional blocks for realizing specific functions which serve as a unit circuits and realize specific function on a semiconductor chip (col. 16, lines 1-55 and col.20, lines 50-51 and Fig. 13); forming a global wiring layer 20 by forming a wiring layer on a semiconductor substrate (col. 15, lines 38-67 and col.16, lines 1-50 and Figs. 12-13); laminating the system LSI cell portion 30 with the global wiring layer 20 such that the functional blocks are electrically connected to each other (col. 15, lines 38-67 and col.16, lines 1-50 and Figs. 12-13) wherein the global wiring layer 20 is formed by sequentially laminating a first wiring layer 16X, a second wiring layer 16Y, an insulating layer 16I, and inner bumps 23 on a semiconductor substrate 10 (col. 15, lines 38-67 and col.16, lines 1-50 and Figs. 12-13).

Regarding claims 7, 9, 18 and 20, Saitou et al., discloses the insulting layer 16I includes a via which electrically connects the first wiring layer 16X with the second wiring layer 16Y (Fig. 12).

Regarding claim 10 and 21, Saitou et al., discloses the global wiring layer 20 has at least one or more of the wiring layers (Figure. 13).

Regarding claims 11 and 22, Saitou et al., discloses the global wiring layer 20 has at least one or more of the insulating layers (Figure. 13).

Page 4

Art Unit: 2818

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quoc Hoang whose telephone number is (703) 306-5795. The examiner can normally be reached on Monday -Friday from 8.00 AM to 5.00 PM.

If attempt to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms., can be reached on (703) 308-4910.

Quoc Hoang

Patent Examiner/AU 2818

David Nelms
Supervisory Patent Examiner
Technology Center 2800